Anomalous behavior in the phonon dispersion of the (001) surface of Bi₂Te₃ determined from helium atom-surface scattering measurements

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We employ inelastic helium atom-surface scattering to measure the low-energy phonon dispersion along high-symmetry directions on the surface of the topological insulator Bi₂Te₃. Results indicate that one particular low-frequency branch experiences noticeable mode softening attributable to the interaction between Dirac fermion quasiparticles and phonons on the surface. This mode softening constitutes a renormalization of the real part of the phonon self-energy. We obtain the imaginary part, and hence lifetime information, via a Hilbert transform. In doing so, we are able to calculate an average branch-specific electron-phonon coupling constant $\langle \lambda_{\nu} \rangle = 1.44$.

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I. INTRODUCTION

The compound Bi_2Te_3 is a strong three-dimensional topological insulator (TI), a recently discovered class of materials with an insulating bulk electronic structure and protected metallic quasiparticle surface states.^{1–5} The surface quasiparticles are found to be Dirac fermions with a single Dirac cone located in the bulk band gap and centered at the $\overline{\Gamma}$ point.⁶ Strong spin-orbit interactions lock the Dirac fermion quasiparticles' (DFQs) spin and wave vector in a mutually perpendicular configuration, giving the Dirac cone a definite chirality. As a result, the surface states are robust against timereversal invariant perturbations. Consequently, DFQs on the surface cannot backscatter from lattice vacancies, grain boundaries, phonons, etc. into their time-reversed counterparts. Despite these constraints, it was recently found that the DFQs strongly interact with surface boson excitations, especially phonon⁷ and coupled plasmon-spin^{8,9} excitations. Technical improvements may minimize defects, but phonons are always present. Consequently, DFQ-phonon interaction should be a dominant scattering mechanism for Dirac fermions on these surfaces at finite temperatures. Hence, the electron-phonon (e-p) interaction is of exceptional importance when assessing the feasibility of promising applications in technologies such as spintronics and quantum computing.

In this paper, we present experimental and theoretical studies of the surface phonon dispersions of Bi₂Te₃ along the high-symmetry directions $\overline{\Gamma}\overline{M}$ and $\overline{\Gamma}\overline{K}\overline{M}$. The experimental measurements were carried out with the aid of elastic and inelastic helium atom-surface scattering (HASS). Phonon mode identification was obtained by fitting the results of lattice dynamics slab calculations, based on the pseudocharge model, to experimental data. To extract information about the *e*-*p* interactions, an expression for the phonon self-energy was derived from a phenomenological model employing the random phase approximation (RPA). The real part of the self-energy was fitted to the experimental results, and subsequently the imaginary part was obtained with the aid of the Kramers-Kronig transformation. This allowed the determination of mode-dependent *e*-*p* coupling, i.e., phonon-branch-specific

 $\lambda_{\nu}(\boldsymbol{q}),$ where the subscript ν indicates the particular branch involved.

The highlights of the study include a strong Kohn anomaly and the absence of long wavelength Rayleigh modes. Moreover, one particular optical surface phonon branch originating at the $\overline{\Gamma}$ point with $\omega \approx 1.4$ THz experiences significant renormalization due to interactions with the DFQs. We fitted our experimental results to lattice dynamical calculations based on the pseudocharge model and found it necessary to introduce a coupling between surface pseudocharge to account for the unique shape of the dispersion. The extracted average value of the branch-specific dimensionless *e-p* coupling constant is $\langle \lambda_{\nu} \rangle = 1.44$.

In Sec. II we discuss the experimental setup and procedures. The formulation of the pseudocharge-based lattice dynamical calculations is presented in Sec. III, while a brief discussion of the RPA machinery is outlined in Sec. IV. Finally, we present the results and discussion in Sec. V.

II. EXPERIMENTAL SETUP AND PROCEDURES

A. Crystal preparation

Polycrystalline Bi2Te3 compounds were prepared by solidstate reaction. High-purity starting elements of Bi (99.999%, chunks) and Te (99.999%, shot) were melted in evacuated carbon coated quartz tubes at 550 °C for 10 h, slowly cooled to 150 °C, followed by a rapid quenching in water. The obtained ingots were pulverized into powder, sealed in evacuated quartz tubes (10 cm length and 1.6 cm inner diameter at $\sim 10^{-3}$ Torr) after multiple argon gas purging cycles, pretreated at 550 °C for 48 h in a box furnace and furnace-cooled. Single crystals were grown with a vertical Bridgman furnace starting from the pretreated sealed tubes. The temperature profile of the Bridgman furnace used for the whole series was maintained at 350–700 °C within a 25 cm region. Initial complete melting was achieved at 700 °C for 24 h to ensure complete reaction and mixing. A temperature gradient of 0.5 °C/cm was programed around the solidification point near 585 °C, and the quartz tube was then slowly lowered into the cooling zone at a rate of 0.5 mm/h. The grown single crystals were 3 cm long and about 1.6 cm in diameter with good optical quality. They are easy to cleave with crystal planes perpendicular to the hexagonal c axis.

Grown crystals of Bi₂Te₃ were cut into wafers approximately 3 mm \times 3 mm \times 1 mm. The wafer was subsequently attached to the oxygen-free high conductivity (OFHC) copper sample holder using ultrahigh vacuum (UHV) compatible conducting epoxy. The sample holder and wafer were baked at 180 °C for approximately 1 h to allow the epoxy to cure. Upon removal, an additional layer of epoxy was added to the top of the wafer onto which a cleaving pin was pressed. The entire assembly consisting of sample holder, wafer, and cleaving pin was again baked for roughly 1 h. After cooling to room temperature, the sample assembly was transferred into the UHV chamber and mounted on a sample manipulator equipped with XYZ motions as well as polar and azimuthal rotations. A base pressure of $\sim 10^{-10}$ Torr was maintained in the chamber with the aid of a liquid nitrogen baffle, a titanium pump, and a turbo molecular pump. The partial pressures of the main contaminants in the chamber (CO, CO_2 , and H_2O) were consistently below 5.0×10^{-11} Torr. The sample was then cleaved in situ by knocking the cleaving pin off the wafer. All measurements were performed with the sample surface at room temperature.

B. Experimental measurements

Experimental measurements of the surface phonon dispersion were carried out at the helium atom-surface scattering facility at Boston University. Elastic diffraction was used to determine the surface structure and its quality, and to orient the sample surface along desired high-symmetry directions. Inelastic surface scattering methods, based on time-of-flight (TOF) techniques, were employed to perform measurements of the phonon dispersion.

The incident helium beam has a velocity resolution of $\approx 1.6\%$ with an angular spread of 0.06°. Detection of the scattered helium and its energy distribution is effected by a metastable atom velocity analyzer. As shown in Fig. 1, the detector¹⁰ is comprised of an electron gun and a multichannel plate (MCP) electron multiplier. The electron gun generates a well-collimated, monoenergetic electron beam crossing the angle-resolved scattered He beam at right angles. The energy of the electron beam is tuned to excite the He atoms to their first excited metastable state (He*, $2^{3}S$, 10^{4} s lifetime) upon impact. Deexcitation of a He* atom at the surface of the MCP leads to the ejection of an electron in a manner similar to Auger emission, which generates an electron cascade that is then collected by the anode of the multiplier. By electronically pulsing the electron gun, a gate function is created for TOF measurements in the inelastic HASS mode. The overall energy resolution of the TOF measurements is about 1 meV. The details of the detection scheme are given in Ref. 10.

By writing the He-atom wave vector as $\mathbf{k} = (\mathbf{K}, k_z)$, where **K** is the component parallel to the surface, conservation of momentum and energy for the "in-scattering-plane" geometry

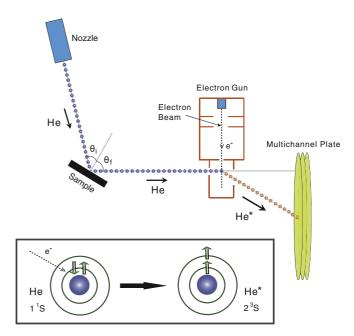


FIG. 1. (Color online) Schematic diagram of the helium beam detection mechanism. The incident beam energy is controlled by the nozzle temperature and the incident and final angles may be adjusted via the polar controls of the sample manipulator and detector, respectively.

can be expressed as

$$\Delta K = |\mathbf{G} + \mathbf{Q}| = k_f \sin \theta_f - k_i \sin \theta_i, \qquad (1)$$

$$\Delta E = \hbar \omega(\mathbf{Q}) = \frac{\hbar^2 k_f^2}{2M} - \frac{\hbar^2 k_i^2}{2M}, \qquad (2)$$

where subscripts *i* and *f* denote incident and scattered beams, respectively, and ΔK is the momentum transfer parallel to the surface. **G** is a surface reciprocal-lattice vector, **Q** is the surface phonon wave vector, $\hbar\omega(\mathbf{Q})$ is the corresponding surface phonon energy, and *M* is the mass of a He atom. By eliminating k_f from the above equations, one obtains the so-called *scan curve* relations which are the locus of all the allowed ΔK and ΔE as dictated by the geometry and the conservation relations,

$$\Delta E = E_i \left[\left(\frac{\sin \theta_i + \Delta K / k_i}{\sin \theta_f} \right)^2 - 1 \right], \tag{3}$$

where $E_i = \hbar^2 k_i^2 / 2M$. Note that the energy exchange ΔE can be both positive and negative, corresponding to phonon annihilation and creation, respectively. A sample set of scan curves for fixed E_i and θ_i but variable θ_f may be seen in Fig. 2. The intersections of these scan curves with the phonon dispersion curves define the kinematically allowed inelastic events for a fixed geometric arrangement. Thus, the geometric scattering configurations for scanning a particular region of ΔE versus ΔK can be preselected. By systematically changing E_i , θ_i , and θ_f , the entire set of dispersion curves along a particular direction in the Brillouin zone can be accessed.

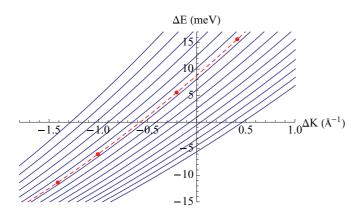


FIG. 2. (Color online) Scan curves showing the kinematically allowed scattering events for $E_i = 43.09$ meV and $\theta_i = 45.62^\circ$. Each blue parabola corresponds to a unique θ_f , which are plotted here in 1° increments from 35° to 50°. The red parabola and data points correspond to the phonon events shown in the third panel of Fig. 8.

III. PSEUDOCHARGE PHONON MODEL

A. Crystal structure

The Bi₂Te₃ primitive cell is shown in Fig. 3. Alternating hexagonal monatomic crystal planes stack in ABC order. Units of Te-Bi-Te-Bi-Te form quintuple layers (QLs): bonding between atomic planes within a QL is covalent, whereas bonding between adjacent QLs is predominantly of the Van der Waals type. The primitive cell contains three QLs. The crystal structure belongs to the space group $R\bar{3}m$. The point group contains a binary axis (with twofold rotation symmetry), a bisectrix axis (appearing in the reflection plane), and a trigonal axis (with threefold rotation symmetry).

The primitive translation vectors in the hexagonal basis are

$$\mathbf{t}_1 = a\left(\frac{\sqrt{3}}{2}, -\frac{1}{2}, 0\right), \, \mathbf{t}_2 = a(0, 1, 0), \, \mathbf{t}_3 = c(0, 0, 1), \quad (4)$$

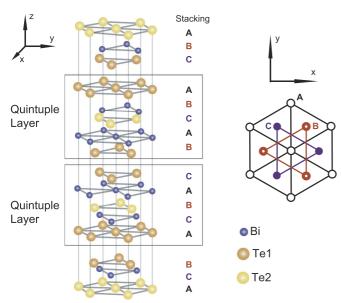


FIG. 3. (Color online) Hexagonal unit cell of the Bi₂Te₃ crystal comprised of three QLs and belonging to the space group $R\bar{3}m$. Note that the Te2 layer within each QL is a center of inversion symmetry.

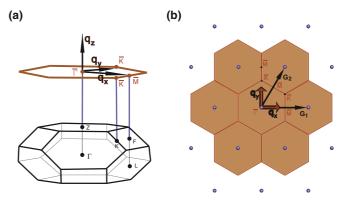


FIG. 4. (Color online) Bulk and surface reciprocal space structure of Bi₂Te₃. Panel (a) shows the bulk Brillouin zone and high-symmetry points. The surface Brillouin zone is represented as a projection along \mathbf{q}_z . The extended surface reciprocal lattice is shown in (b) depicting high-symmetry points $\overline{\Gamma}, \overline{M}$, and \overline{K} as well as reciprocal-lattice vectors \mathbf{G}_1 and \mathbf{G}_2 .

where *a* and *c* are lattice constants of the hexagonal cell. The corresponding reciprocal-lattice vectors are

$$\mathbf{G}_{1} = \frac{2\pi}{a} \left(\frac{2}{\sqrt{3}}, 0, 0 \right), \quad \mathbf{G}_{2} = \frac{2\pi}{a} \left(\frac{1}{\sqrt{3}}, 1, 0 \right),$$

$$\mathbf{G}_{3} = \frac{2\pi}{c} (0, 0, 1).$$
 (5)

The reciprocal space structure of Bi_2Te_3 is shown in Fig. 4.

B. Equations of motion

To identify the character and symmetry of the measured inelastic events, we employ empirical lattice dynamics slab calculations, based on the pseudocharge model (PCM).^{11–13} With this procedure, we characterize and further substantiate our measurements of the phonon dispersion of Bi_2Te_3 . Here we review some of its basic characteristics and tabulate the parameters used in our realization of the model.

To begin, we expand the electron density n_l within each primitive cell l in terms of symmetry-adapted multipole components around selected Wyckoff symmetry points \mathbf{R}_{l_i} ,

$$n_l(\mathbf{r}) = \sum_{j \Gamma k} c_{\Gamma k}(lj) Y_{\Gamma k}(\mathbf{r} - \mathbf{R}_{lj}), \tag{6}$$

where Γ denotes an irreducible representation (irrep) of the Wyckoff symmetry point group and *k* indexes its rows; $Y_{\Gamma k}$ is a symmetry-adapted harmonic function. The expansion coefficients $c_{\Gamma k}$ are separated into static and dynamic components, the latter being treated as bona fide time-dependent dynamical variables,

$$c_{\Gamma k}(lj;t) = c_{\Gamma k}^{(0)}(lj) + \Delta c_{\Gamma k}(lj;t).$$
(7)

We note that the static components $c_{\Gamma k}^{(0)}(lj)$ at equivalent positions j will be identical, however their dynamical counterparts $\Delta c_{\Gamma k}(lj;t)$ will vary with both l and j.

We may write the Lagrangian of the combined pseudocharge-ion system as

$$\mathcal{L} = \frac{1}{2} \left(\sum_{l\kappa\alpha} M_{\kappa} \dot{u}_{\alpha}^{2}(l\kappa) + \sum_{\substack{\Gamma k \\ lj}} m_{\Gamma} \Delta \dot{c}_{\Gamma k}^{2}(lj) \right) - \left(\frac{1}{2} [\mathbf{u} \cdot \mathbf{\Phi} \cdot \mathbf{u} + (\mathbf{u} \cdot \mathbf{T} \cdot \Delta \mathbf{c} + \mathbf{h.c.}) + \Delta \mathbf{c} \cdot \mathbf{H} \cdot \Delta \mathbf{c}] \right).$$
(8)

The kinetic term contains contributions from both the ions and pseudocharge (PC) where $u_{\alpha}(l\kappa)$ is the displacement in the α direction of the ion at site κ in unit cell *l*; *M* is the ionic mass and m_{Γ} is an effective PC mass that will be set to zero upon invoking the adiabatic approximation. The potential energy is expanded in a Taylor series to second order in the ion (PC) displacements (deformations). Φ , **T**, and **H** are empirical force-constant matrices representing ion-ion, ion-PC, and PC-PC interactions, respectively.

We obtain the Euler-Lagrange equations of motion for the ions and PCs in the standard way,

$$M_{\kappa}\ddot{u}_{\alpha}(l\kappa) = -\sum_{l'\kappa'\beta} \Phi_{\alpha\beta} \binom{l\ l'}{\kappa\ \kappa'} u_{\beta}(l'\kappa') -\sum_{\substack{l'j\\\Gamma k}} T_{\alpha} \binom{l\ l'}{\kappa\ j} \Delta c_{\Gamma k}(l'j), \qquad (9)$$

$$m_{\Gamma}\Delta\ddot{c}_{\Gamma k}(lj) = -\sum_{l'\kappa'\alpha} T_{\Gamma k} \begin{pmatrix} l \ l' \\ j \ \kappa' \end{pmatrix} u_{\alpha}(l'\kappa') -\sum_{l'j'} H_{\Gamma k} \begin{pmatrix} l \ l' \\ j \ j' \end{pmatrix} \Delta c_{\Gamma k}(l'j'), \quad (10)$$

noting that only PCs belonging to the same irrep and the same row can couple.

C. Adiabatic approximation, ionic self-terms, and PC self-terms

The entries of the matrix Φ are expressed in terms of empirical parameters. However, the diagonal, self-term, elements that determine how the displacement of a particular ion affects its own motion must be treated carefully. We approach this case by first invoking the adiabatic approximation in which we set $m_{\Gamma} = 0$. This is equivalent to saying that the electronic response to lattice deformations is instantaneous. We then have

$$\Delta \mathbf{c} = -\mathbf{H}^{-1}\mathbf{T}^T\mathbf{u}.$$
 (11)

We now note that the crystal is invariant under an arbitrary rigid displacement \mathbf{u}_0 . In this scenario, we have

$$\Delta \mathbf{c} = -\mathbf{H}^{-1}\mathbf{T}^T \mathbf{u}_{\mathbf{0}}.$$
 (12)

Substituting for Δc in (9), we obtain

$$\mathbf{0} = -\mathbf{\Phi}\mathbf{u}_{\mathbf{0}} + \mathbf{T}\mathbf{H}^{-1}\mathbf{T}^{T}\mathbf{u}_{\mathbf{0}},\tag{13}$$

where **0** is a null column matrix of length 3N, where *N* is the number of ions. Equation (13) is actually satisfied for each 3×3 ionic matrix and any arbitrary displacement, provided it

is uniform. Thus, we rearrange and separate the self-term from the rest of the sum to obtain

$$\Phi\begin{pmatrix} l \ l \\ \kappa\kappa \end{pmatrix} = -\sum_{l'\kappa'}^{\prime} \Phi\begin{pmatrix} l \ l' \\ \kappa\kappa' \end{pmatrix} + \sum_{\substack{l'jj'\\\Gamma k}} \mathbf{T}_{\Gamma k} \begin{pmatrix} l \ l' \\ \kappa j \end{pmatrix} \mathbf{H}_{\Gamma k}^{-1} \begin{pmatrix} l \ l' \\ jj' \end{pmatrix} \mathbf{T}_{\Gamma k}^{T} \begin{pmatrix} l \ l' \\ \kappa j \end{pmatrix}, \quad (14)$$

where the prime on the first sum indicates that the self-term is excluded.

We proceed in a similar manner to calculate the diagonal elements of the matrix **H**. We again employ translational invariance, but this time we explicitly choose our rigid displacement to be in the *z* direction for clarity. We can rewrite Eq. (10) as

$$0 = -\sum_{l'\kappa'} T_{\Gamma k} \begin{pmatrix} l \ l' \\ j \ \kappa' \end{pmatrix} u_{z}(l'\kappa') - \sum_{l'j'} H_{\Gamma k} \begin{pmatrix} l \ l' \\ j \ j' \end{pmatrix} \Delta c_{\Gamma k}(l'j').$$
(15)

We separate the PC self-term from the rest of the sum and rearrange to obtain

$$H_{\Gamma k} \begin{pmatrix} l \ l \\ j \ j \end{pmatrix} = \frac{-1}{\Delta c_{\Gamma k}(l,j)} \left[\sum_{l'\kappa'} T_z \begin{pmatrix} l \ l' \\ j \ \kappa' \end{pmatrix} u_z(l',\kappa') + \sum_{l'j'}^{\prime} H \begin{pmatrix} l \ l' \\ j \ j' \end{pmatrix} \Delta c_{\Gamma k}(l',j') \right].$$
(16)

For a rigid displacement of the entire crystal (including the PC) in the *z* direction, we have $\Delta c_{\Gamma k} = u_z = u_0$ for all l, κ, j . The PC self-term then takes the form

$$H_{\Gamma k} \begin{pmatrix} l \ l \\ j \ j \end{pmatrix} = -\sum_{l' \kappa'} T_z \begin{pmatrix} l \ l' \\ j \ \kappa' \end{pmatrix} - \sum_{l' j'} H_{\Gamma k} \begin{pmatrix} l \ l' \\ j \ j' \end{pmatrix}.$$
(17)

With the ionic and PC self-terms fixed, we are now in a position to calculate the phonon frequencies. Fourier transforming Eq. (9), scaling the force-constant matrices by the ionic masses, and employing Eq. (11) yields

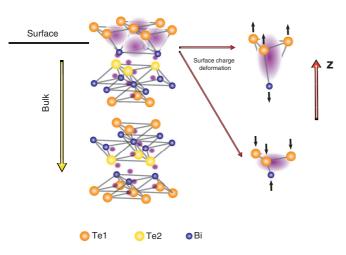
$$\omega^{2}(\mathbf{q})\mathbf{u}(\mathbf{q}) = \mathcal{D}(\mathbf{q})\mathbf{u}(\mathbf{q}),$$

$$\mathcal{D}(\mathbf{q}) = \mathbf{\Phi}(\mathbf{q}) - \mathbf{T}(\mathbf{q})\mathbf{H}^{-1}(\mathbf{q})\mathbf{T}^{\dagger}(\mathbf{q}).$$
(18)

Thus, to determine the phonon frequencies at a particular wave vector, one needs only to construct the dynamical matrix $\mathcal{D}(\mathbf{q})$ and find its eigenvalues.

D. Bulk and surface parameters

In our computational model, first the ionic positions are populated. As for the PCs, the "*c*" Wyckoff positions of the $R\bar{3}m$ space group, with C_{3v} point-group symmetry, were the most appropriate to use as centers of PC symmetryadapted multipole expansion. They are identified as having coordinates $(0, 0, \pm z)$ that define the vertical axes of the tetrahedral pyramids shown in Fig. 5. The pyramid centers were chosen as PC expansion points. C_{3v} has irreps A_1 (with dipolar symmetry-adapted harmonic z) and E (with dipolar



Pseudocharge Model

FIG. 5. (Color online) Schematic diagram of ion and PC locations in the PCM. The figure indicates that the surface PC are more spread and easier to deform than their bulk counterparts. The figures to the right show the dipolar PC deformation associated with lattice distortions along the z direction.

symmetry-adapted harmonics x, y). To minimize the number of empirical constants employed in the bulk calculations, we opted to include only the A_1 symmetry-adapted fluctuations as depicted in Fig. 5, which also shows the ion and PC locations in the PCM.

In the insulating bulk, we do not include interactions between PCs, rendering **H** diagonal and constrained by Eq. (17). However, we introduce two force-constant parameters T_z^1 and T_z^2 to account for the ion-PC coupling in pyramids involving Te1-Bi and Te2-Bi, respectively. We use central ion-ion interaction potentials v(r) with force-constant matrix elements of the form

$$\Phi_{\alpha\beta} = A \frac{x_{\alpha} x_{\beta}}{r_0^2} - B \left(\frac{x_{\alpha} x_{\beta}}{r_0^3} - \frac{1}{r_0} \delta_{\alpha\beta} \right).$$
(19)

The parameters A and B are related to the ion potential via

$$A = \frac{\partial^2 v}{\partial r^2} \Big|_{r=r_0}, \quad B = \frac{\partial v}{\partial r} \Big|_{r=r_0}, \quad (20)$$

where r_0 is the equilibrium bond length. We consider only nearest-neighbor interactions for Bi-Te couplings. However, because of the large size of Bi atoms, we admit coupling to their nearest in-plane (intralayer) Bi neighbors, which are actually second neighbors, as well as to the nearest Bi atom in the other

TABLE I. Bulk parameters for the lattice dynamical calculations based on the PCM.

Ion-ion interaction			Ion-PC interaction	
A (N/m)	<i>B</i> (N)	Position	Value (N/m)	
0.187 0.99 0.2 0.2	0.0187 0.099 0.02 0.02	$\frac{T_z^1 \text{ (Te1-Bi)}}{T_z^2 \text{ (Te2-Bi)}}$	0.35 0.4	
	A (N/m) 0.187 0.99 0.2	A (N/m) B (N) 0.187 0.0187 0.99 0.099 0.2 0.02 0.2 0.02	A (N/m) B (N) Position 0.187 0.0187 T_z^1 (Te1-Bi) 0.99 0.099 T_z^2 (Te2-Bi) 0.2 0.02 0.2 0.02	

Bi layer within a single QL (interlayer). To determine the forceconstant and PC parameters, we fit our bulk phonon calculation to available Raman, IR, and inelastic neutron spectroscopy data.^{14–17} A summary of the parameters used and their values are given in Table I.

The best fit to the available bulk data is shown in Figs. 6(a)– 6(d). Dispersions are presented along three high-symmetry directions Λ (Γ -Z), Δ (Γ -X), and Σ (Γ -Y). Raman, IR, and neutron data are depicted as red triangles, green squares, and blue circles, respectively. The calculations agree well with all data types at the Γ point. However, we note some discrepancies between our calculations and the neutron data for some optical branches. First, there is disagreement in the dispersion of the low-energy E_u and E_g optical modes along the Λ direction. Introduction of E PC deformations would

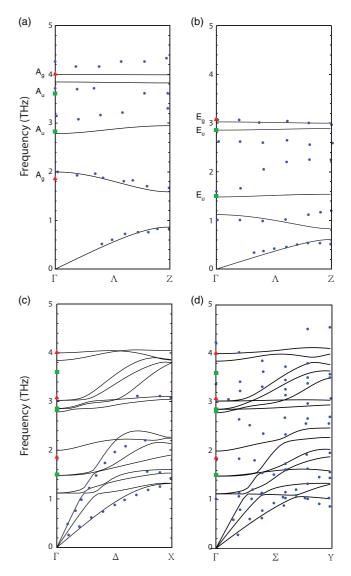


FIG. 6. (Color online) Calculated bulk dispersion curves along the high-symmetry directions Λ [(a) and (b)], Δ (c), and Σ (d). The C_{3v} symmetry of the Λ direction allows one to project out purely longitudinal A modes and doubly degenerate, transverse E modes. Modes along the Δ and Σ directions have mixed polarization. The calculated dispersions were fit to available Raman (red triangles), IR (green squares), and inelastic neutron scattering (blue circles) data.

TABLE II. Modified surface parameters for the lattice dynamical calculations.

Surface ion-ion interaction			Surface ion-PC interaction			
Bond	A (N/m)	<i>B</i> (N)	Position	Value (N//m)		
Te1-Bi	0.42	0.042	T_z^{S} (Te1-Bi)	0.24		
Te1-Te1 (intra)	0.25	0.025	T_{xy}^{S} (Te1-Bi)	0.15		
			\tilde{T}_{xy}^{S} (Te2-Bi)	0.4		
Surface PC-PC interaction						
$H_q = H_0(1 + \frac{q^2}{a}e^{-q^2/b}), H_0 = -0.0782, a = 0.0034, b = 0.0075$						

not remedy this, since they involve interactions in the x/y plane and will not introduce the necessary phases along the Λ (*z*) direction. We believe that the remedy for this discrepancy would be the introduction of long-range Coulomb interactions, as suggested by a previous study¹⁵ of bulk Bi₂Te₃. However, since we are primarily concerned with the surface, where Coulomb interactions are effectively screened by DFQs, we opted not to include such interactions. Second, we note some disagreements and ambiguities between the calculations and neutron data for the dispersions of high-energy optical modes along the Σ direction. In this case, the inclusion of *E* PC deformations might improve the fitting. Yet we opted to omit these deformations since we are primarily interested in the low-energy sector where the Kohn anomaly appears and there is reasonable agreement.

In calculating the surface phonon dispersions, we employed a slab geometry containing 30 QLs. To obtain the best fit to the experimental data, the following changes and additions to the bulk parameter values were made:

(i) The surface Te1-Bi force-constant parameter was reduced to roughly 42% of its bulk value to account for the reduced bonding and the emergence of metallic electrons.

(ii) A new planar force-constant parameter involving intralayer surface Te1-Te1 bonds was introduced.

(iii) Symmetry-adapted x/y deformations of the PC in the surface and subsurface pyramids, which form a basis of the doubly degenerate irrep E, were introduced to account for the delocalized nature of the DFQs. These are effected via new parameters T_{xy}^{S} and \tilde{T}_{xy}^{S} , respectively. In addition, T_{z}^{S} was reduced from its bulk value to account for the extra screening provided by the DFQ surface states.

(iv) A momentum-dependent coupling H_q between dipolar z deformations of neighboring surface PC was introduced to account for interactions among the DFQs.

The surface parameters are summarized in Table II. Calculated dispersions for the slab geometry are presented in Sec. V.

IV. CALCULATION OF *e-p* COUPLING CONSTANT IN THE RANDOM PHASE APPROXIMATION

In this section, we describe the phenomenological modelfitting approach to the experimentally measured dispersion of the optical phonon branch that exhibits strong *e*-*p* renormalization, and the procedure followed to extract the corresponding *e*-*p* coupling function $\lambda_{\nu}(\mathbf{q})$. The construction of the model is carried out with the aid of the RPA. We start by defining the noninteracting, or free, surface phonons Hamiltonian in second-quantized form,

$$\mathcal{H}_{\rm ph} = \sum_{\mathbf{q},\nu} \hbar \omega_{\mathbf{q},\nu}^{(0)} \left(b_{\mathbf{q},\nu}^{\dagger} \, b_{\mathbf{q},\nu} + \frac{1}{2} \right),\tag{21}$$

where $b_{\mathbf{q},\nu}^{\dagger}$ is the creation operator of a phonon of bare frequency $\omega_{\mathbf{q},\nu}^{(0)}$ and branch index ν . The free phonon Matsubara Green's function of the (\mathbf{q},ν) mode is defined as

$$\mathcal{D}_{\nu}^{(0)}(\mathbf{q}, i\omega_n) = \frac{2(\hbar\omega_{\mathbf{q},\nu}^{(0)})}{(i\omega_n)^2 - (\hbar\omega_{\mathbf{q},\nu}^{(0)})^2},$$
(22)

where $i\omega_n$ is the Matsubara frequency.

The electronic surface states of Bi_2Te_3 form a twodimensional Dirac metal, whose low-energy physics is well described by the Hamiltonian

$$\mathcal{H}_{\rm el} = \sum_{\mathbf{k}} \psi_{\mathbf{k}}^{\dagger} \left[\hbar v_F \, \hat{\mathbf{z}} \cdot (\mathbf{k} \times \boldsymbol{\sigma}) - \mu \right] \psi_{\mathbf{k}}, \qquad (23)$$

where $\psi_{\mathbf{k}} \equiv \begin{pmatrix} c_{\mathbf{k}\uparrow} \\ c_{\mathbf{k}\downarrow} \end{pmatrix}$ is the two-component electron spinor operator at wave vector \mathbf{k} , v_F is the Fermi velocity, μ is the Fermi energy (which lies above the Dirac point), and $\boldsymbol{\sigma} = (\sigma_1, \sigma_2)$ is the vector containing the first two Pauli matrices. The Dirac Hamiltonian (23) is diagonal in the helicity basis $\Psi_{\mathbf{k}} = \begin{pmatrix} \gamma_{\mathbf{k}}^{+} \\ \gamma_{\mathbf{k}} \end{pmatrix}$:

$$\Psi_{\mathbf{k}} = U_{\mathbf{k}} \, \psi_{\mathbf{k}},$$
$$U_{\mathbf{k}} = \frac{1}{\sqrt{2}} \begin{pmatrix} i e^{i\varphi_{\mathbf{k}}} & 1\\ -i e^{i\varphi_{\mathbf{k}}} & 1 \end{pmatrix}, \quad \varphi_{\mathbf{k}} \equiv \arctan\left(\frac{k_{y}}{k_{x}}\right) \quad (24)$$

yielding

$$\mathcal{H}_{\rm el} = \sum_{\mathbf{k}} \sum_{\alpha = \pm} \xi_{\mathbf{k}}^{\alpha} (\gamma_{\mathbf{k}}^{\alpha})^{\dagger} \gamma_{\mathbf{k}}^{\alpha}, \quad \xi_{\mathbf{k}}^{\alpha} = \alpha \hbar v_F |\mathbf{k}| - \mu. \quad (25)$$

We consider an interaction between the electron density and the displacement \mathbf{u}_j of the *j*th ion about its in-plane equilibrium position $\mathbf{R}_j^{(0)}$. The displacement \mathbf{u}_j has both in-plane and out-of-plane components. The *e*-*p* interaction can be generically written as

$$\mathcal{H}_{e-p} = \int d^2 \mathbf{r} \, \rho_e(\mathbf{r}) \, \sum_j \, \boldsymbol{\eta} \left(\mathbf{r} - \mathbf{R}_j^{(0)} \right) \cdot \mathbf{u}_j, \qquad (26)$$

where $\rho_e(\mathbf{r}) = \sum_{\sigma=\uparrow,\downarrow} c_{\sigma}^{\dagger}(\mathbf{r}) c_{\sigma}(\mathbf{r})$ is the electron surface density operator and $\boldsymbol{\eta}(\mathbf{r} - \mathbf{R}_j^{(0)})$ is a position-dependent vector function (with units of energy per length) characterizing the *e*-*p* coupling. The quantities $\rho_{\rm el}$, $\boldsymbol{\eta}$, and \mathbf{u}_j are then expanded in reciprocal space as

$$\begin{split} \eta \left(\mathbf{r} - \mathbf{R}_{j}^{(0)} \right) &= \frac{1}{\mathcal{A}} \sum_{\mathbf{q}} \eta_{\mathbf{q}} e^{i\mathbf{q} \cdot (\mathbf{r} - \mathbf{R}_{j}^{(0)})}, \\ \rho_{e}(\mathbf{r}) &= \sum_{\sigma=\uparrow,\downarrow} c_{\sigma}^{\dagger}(\mathbf{r}) c_{\sigma}(\mathbf{r}) \\ &= \frac{1}{\mathcal{A}} \sum_{\sigma=\uparrow,\downarrow} \sum_{\mathbf{q}} e^{-i\mathbf{q} \cdot \mathbf{r}} \sum_{\mathbf{k}} c_{\mathbf{k}+\mathbf{q},\sigma}^{\dagger} c_{\mathbf{k},\sigma}, \\ \mathbf{u}_{j} &= \frac{1}{\sqrt{N}} \sum_{\mathbf{q},\nu} \sqrt{\frac{\hbar}{2M\omega_{\mathbf{q},\nu}^{(0)}}} e^{i\mathbf{q} \cdot \mathbf{R}_{j}^{(0)}} (b_{\mathbf{q},\nu} + b_{-\mathbf{q},\nu}^{\dagger}) \hat{\mathbf{e}}_{\nu}(\mathbf{q}), \end{split}$$

where *N* is the number of surface primitive cells and $\hat{\mathbf{e}}_{\nu}(\mathbf{q})$ is the polarization vector. Substitution in (26) leads to the *e*-*p* interaction Hamiltonian

$$\mathcal{H}_{e-p} = \frac{1}{\sqrt{\mathcal{A}}} \sum_{\sigma=\uparrow,\downarrow} \sum_{\mathbf{k}} \sum_{\mathbf{q},\nu} g_{\mathbf{q},\nu} c^{\dagger}_{\mathbf{k}+\mathbf{q},\sigma} c_{\mathbf{k},\sigma} (b_{\mathbf{q},\nu} + b^{\dagger}_{-\mathbf{q},\nu})$$
(27)

with the e-p coupling

$$g_{\mathbf{q},\nu} = \sqrt{\frac{N\hbar}{2M\mathcal{A}\,\omega_{\mathbf{q},\nu}^{(0)}}} \,\eta_{\mathbf{q}}\cdot\hat{\mathbf{e}}_{\nu}(\mathbf{q}) \equiv \sqrt{\frac{N\hbar}{2M\mathcal{A}\,\omega_{\mathbf{q},\nu}^{(0)}}} \,\eta_{\mathbf{q},\nu}.$$

The dressed phonon Green function \mathcal{D}_{ν} is obtained from the following diagrammatic equation:

$$\mathcal{D}_{\nu} = \mathcal{D}_{\nu}^{(0)} + \mathcal{D}_{\nu}^{(0)} \frac{|\mathbf{g}_{\nu}|^{2}}{\varepsilon} \Pi \mathcal{D}_{\nu}$$

where $|g_{\nu}|^2/\varepsilon$ represents the vertex interactions and the RPA bubble is the electron polarization function defined as

$$\Pi(\mathbf{q}, i\omega_n) = \frac{1}{\mathcal{A}} \frac{1}{\beta} \sum_{i\Omega_m} \sum_{\mathbf{p}} \operatorname{Tr} \big[G_{\sigma, \sigma'}^{(0)}(\mathbf{p} + \mathbf{q}, i\Omega_m + i\omega_n) \\ \times G_{\sigma, \sigma'}^{(0)}(\mathbf{p}, i\Omega_m) \big],$$
(28)

where \mathcal{A} is the surface area and Tr acts on the spin degrees of freedom $\sigma, \sigma' = \uparrow, \downarrow$. $G^{(0)}$ is the noninteracting electronic Matsubara Green's function with fermionic Matsubara frequencies Ω_m ,

$$G_{\sigma,\sigma'}^{(0)}(\mathbf{p},i\Omega_m) = -\int_0^\beta d\tau \, e^{\,\mathrm{i}\Omega_m\tau} \, \langle \, T_\tau \, c_{\mathbf{p},\,\sigma}(\tau) \, c_{\mathbf{p},\,\sigma'}^\dagger(0) \, \rangle_0,$$
(29)

where $\beta \equiv 1/k_B T$ and T_{τ} is the imaginary time-ordering operator. Upon performing the Matsubara sums in Eq. (28), we arrive at

$$\Pi(\mathbf{q}, i\omega_n) = \int \frac{d^2 \mathbf{k}}{(2\pi)^2} \frac{1 + \cos\theta}{2} \\ \times \left[\frac{n_F(\xi_{\mathbf{k}+\mathbf{q}}^+) - n_F(\xi_{\mathbf{k}}^+)}{\xi_{\mathbf{k}+\mathbf{q}}^+ - \xi_{\mathbf{k}}^+ - i\omega_n} + \frac{n_F(\xi_{\mathbf{k}+\mathbf{q}}^-) - n_F(\xi_{\mathbf{k}}^-)}{\xi_{\mathbf{k}+\mathbf{q}}^- - \xi_{\mathbf{k}}^- - i\omega_n} \right],$$
(30)

where ξ^+ and ξ^- were defined in Eq. (25), n_F is the Fermi function, and θ is the angle between wave vectors **k** and **k** + **q**. The factor $(1 + \cos \theta)$ accounts for the effect of DFQ chirality introduced by strong spin-orbit coupling. As such, we note here that the contribution of the spin-orbit interaction to the *e*-*p* coupling is manifest explicitly in the polarization, or response, function as well as implicitly in the strong vertex interactions. In contrast, a recent study¹⁸ of the *e*-*p* coupling in ultrathin Bi films, using density functional perturbation theory, reports that the spin-orbit coupling mainly operates through the vertex terms rather than through the response function. We believe that the difference arises from the fact that, in topological insulators like Bi₂Te₃, the very existence of DFQs and their chirality is a direct manifestation of spin-orbit coupling, which is clearly reflected in the response function. The RPA dielectric function is given by

$$\varepsilon(\mathbf{q}, i\omega_n) = 1 - v_c(\mathbf{q}) \Pi(\mathbf{q}, i\omega_n), \qquad (31)$$

where $v_c(\mathbf{q}) = \frac{e^2}{2\varepsilon_0|\mathbf{q}|}$ is the two-dimensional Fourier transform of the electron-electron Coulomb interaction potential. Solving the diagrammatic equation above yields

$$\mathcal{D}_{\nu}(\mathbf{q}, i\omega_{n}) = \frac{\mathcal{D}_{\nu}^{(0)}(\mathbf{q}, i\omega_{n})}{1 - \mathcal{D}_{\nu}^{(0)}(\mathbf{q}, i\omega_{n}) |\mathbf{g}_{\mathbf{q}, \nu}|^{2} \frac{\Pi(\mathbf{q}, i\omega_{n})}{\varepsilon(\mathbf{q}, i\omega_{n})}}{2(\hbar\omega_{\mathbf{q}, \nu}^{(0)})^{2} - (\hbar\omega_{\mathbf{q}, \nu}^{(0)})^{2} - 2(\hbar\omega_{\mathbf{q}, \nu}^{(0)})\tilde{\Pi}}$$
(32)

with

$$\tilde{\Pi} = |g_{\mathbf{q},\nu}|^2 \frac{\Pi(\mathbf{q},i\omega_n)}{\varepsilon(\mathbf{q},i\omega_n)}$$

being the phonon self-energy.

After performing the analytic continuation $i\omega_n \rightarrow \omega + i0^+$, we obtain the renormalized frequencies as the real part of

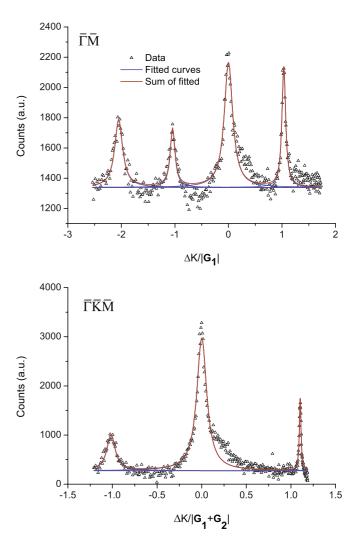


FIG. 7. (Color online) Diffraction patterns indicating the two high-symmetry directions $\overline{\Gamma}\overline{M}$ and $\overline{\Gamma}\overline{K}\overline{M}$ on the surface of Bi₂Te₃. The horizontal axis depicts momentum transfer as a fraction of the pertinent lattice vector.

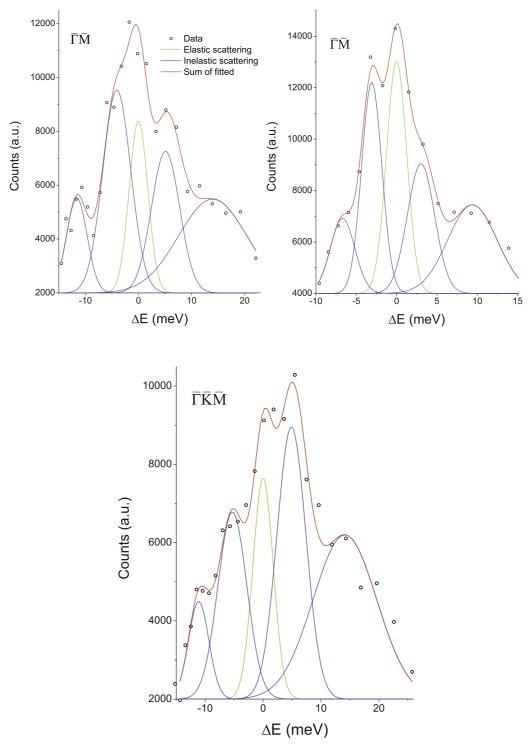


FIG. 8. (Color online) Time-of-flight scans for the inelastic HASS measurements. The abscissa has been converted to energy difference for clarity. Phonon creation and annihilation events are manifest as blue inelastic peaks.

the poles of $\mathcal{D}_{\nu}(\mathbf{q},\omega)$,

$$(\hbar\omega_{\mathbf{q},\nu})^2 = (\hbar\omega_{\mathbf{q},\nu}^{(0)})^2 + 2(\hbar\omega_{\mathbf{q},\nu}^{(0)}) \operatorname{Re}[\tilde{\Pi}(\mathbf{q},\omega_{\mathbf{q},\nu})]. \quad (33)$$

Re $[\Pi(\mathbf{q}, \omega_{\mathbf{q},\nu})]$ is then adjusted to reproduce the measured phonon dispersion. It depends on two parameters, namely the two components of the coupling function $\boldsymbol{\eta} = (\eta_{\perp} \text{ and } \eta_{\parallel})$ which lie in the sagittal plane with directions normal and

parallel to the wave vector **q**. A detailed definition of these couplings is given in Ref. 7. The values of the bare phonon frequency $\omega^{(0)}$ and k_F are extracted from experimental results. The former is identified as the experimental value of ω (**q** = 0) = 1.4 THz, where the DFQ response vanishes, while $2k_F$ was set as the wave vector where the V-shaped Kohn anomaly occurs.¹⁹

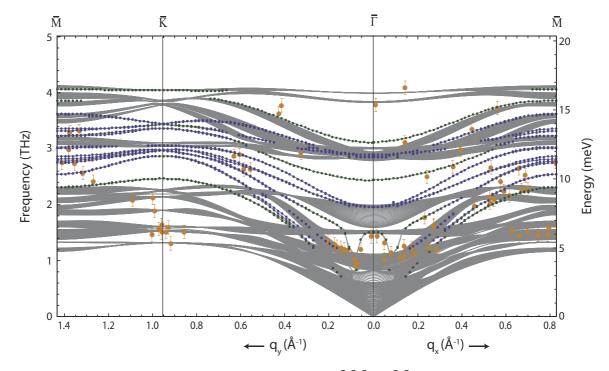


FIG. 9. (Color online) Phonon dispersion along high-symmetry directions $\Gamma \bar{K} \bar{M}$ and $\Gamma \bar{M}$ for Bi₂Te₃. Gray areas represent the projection of bulk phonon bands onto the surface Brillouin zone, whereas the dotted lines indicate surface phonon modes with at least 30% of the oscillator strength concentrated within the first three layers of the 30 QL slab surface regions. Green and blue dots indicate modes polarized perpendicular and parallel to the surface plane, respectively. The TOF measurements are depicted as orange dots with error bars.

After fitting Re[$\tilde{\Pi}(\mathbf{q}, \omega_{\mathbf{q},\nu})$] to the experimental dispersion curve, the corresponding Im[$\tilde{\Pi}(\mathbf{q}, \omega_{\mathbf{q},\nu})$] is obtained by a Kramers-Kronig transformation

$$\operatorname{Im}[\tilde{\Pi}(\mathbf{q},\omega_{\mathbf{q}})] = \frac{2}{\pi} \int_{0}^{\infty} \frac{\omega_{\mathbf{q}}}{\omega_{\mathbf{q}}^{2} - \omega_{\mathbf{q}}^{\prime 2}} \operatorname{Re}[\tilde{\Pi}(\mathbf{q},\omega_{\mathbf{q}}^{\prime})] \, d\omega_{\mathbf{q}}^{\prime}.$$
 (34)

Finally, the e-p coupling function is obtained from the relation²⁰⁻²²

$$\lambda_{\nu}(\mathbf{q}) = -\frac{\mathrm{Im}[\Pi(\mathbf{q}, \omega_{\mathbf{q}, \nu})]}{\pi \mathcal{N}(E_F)(\hbar \omega_{\mathbf{q}, \nu})^2},\tag{35}$$

where $\mathcal{N}(E_F)$ is the density of electronic states at the Fermi surface.

V. EXPERIMENTAL RESULTS AND DISCUSSION

We begin by presenting in Fig. 7 typical diffraction patterns for both the $\overline{\Gamma}\overline{M}$ and $\overline{\Gamma}\overline{K}\overline{M}$ directions. The data show good agreement with the values of the nominal lattice vectors. As was stated earlier, measurements of the phonon dispersion are obtained using inelastic HASS measurements and TOF techniques. Typical TOF scans collected along different highsymmetry directions are shown in Fig. 8.

The measured and computed dispersion curves for Bi_2Te_3 are presented along the two high-symmetry directions in Fig. 9. Gray areas represent the projection of bulk phonon bands onto the surface Brillouin zone, whereas dotted lines indicate surface phonon modes with at least 30% of the oscillator strength (determined by the square of the mode eigenvector) concentrated within the first three atomic layers of the slab surface regions. Green and blue dots signify z-polarized and x/y-polarized modes, respectively. There are two key features worth noting from the onset. First, we notice an optical surface phonon branch (hereon denoted v) originating at approximately 1.4 THz at the $\overline{\Gamma}$ point that disperses to lower energy with increasing wave vector in both the $\overline{\Gamma}\overline{M}$ and $\overline{\Gamma}\overline{K}$ directions. This trend terminates in a V-shaped minimum at $q \approx 0.08$ Å⁻¹ and $\omega \approx 1$ THz, signifying a Kohn anomaly. This is consistent with our previous work⁷ on Bi_2Se_3 , which exhibited a similar Kohn anomaly terminating at $q \approx 0.2$ Å⁻¹. As before, we attribute this phonon mode softening to an effective screening provided by scattering of the DFQs at the Fermi surface, which are schematically depicted in Fig. 10. Scattering events with a momentum transfer greater than the diameter of the Fermi surface require energy, and are therefore suppressed. This is manifest as the recovery of the ν -branch dispersion after $q = 2k_F \approx 0.08$ Å⁻¹. Hence we have an operative DFQ screening for $q < 2k_F$ which is attenuated for wave vectors above this value.¹⁹

We also note the absence of surface acoustic phonon modes in both the measured and computed dispersion, which is also consistent with our results in Bi₂Se₃. It appears that acoustic phonon modes with $q < 2k_F$ are confined to the insulating bulk, unable to penetrate into the metallic surface layers due to mismatch in force constants at the interface. However, for $q > 2k_F$, these acoustic modes may resonate in the metallic film with their bulk counterparts as evidenced by the emergence of the *z*-polarized Rayleigh mode at $\omega \approx 0.8$ THz. We would like to point out that a recent study using density functional theory²³ has also demonstrated the absence of long-wavelength Rayleigh modes in the phonon dispersion. However, we should

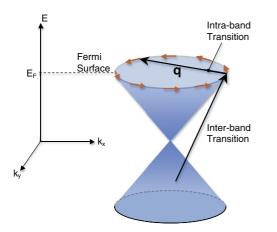


FIG. 10. (Color online) Diagram showing the dispersion of the surface DFQ excitations. The spin chirality of the Fermi surface is depicted by the red arrows. The screening effects of the DFQs can be understood in terms of the scattering of electrons in the Dirac cone with the momentum transfer supplied by a phonon. We identify two distinct types of transitions: intraband and interband, although the latter are suppressed by energetic considerations. Note that low-energy intraband transitions are confined to a circle of diameter $2k_F$.

note that the authors' results are for Bi_2Te_3 thin films (two to three QLs), so the connection to the current work may be tenuous. Indeed, the study also yields a value for the average e-p coupling constant that is significantly smaller than the result presented here.

One may question why there are several low-energy measured events that do not overlap with any computed surface phonon modes. This may be attributable to the large phonon density of states associated with a high concentration of flat, narrow projected bulk bands. It may be possible that we are sampling these bulk modes via surface resonances.

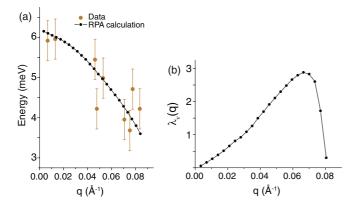


FIG. 11. (Color online) (a) Plot depicting the renormalization of the ν -branch energy in the range $0 < q < 2k_F$. The dotted black lines indicate the renormalized phonon frequencies in the RPA calculation given by Eq. (33), which are fit to experimental data (orange points). (b) Plot of the ν -branch-specific coupling function. The steady increase of $\lambda_{\nu}(\mathbf{q})$ with \mathbf{q} is consistent with the softening of the ν -branch phonon frequencies. The attenuation just before $q \approx 2k_F$ is due to the fact that scattering of DFQs across the Fermi surface by phonons is not possible due to time-reversal invariance.

To make quantitative statements about the magnitude of the *e-p* coupling on the surface of Bi₂Te₃, we fit the real part of the phonon self-energy to our experimental data as described in Sec. IV. Figure 11(a) depicts the results where we overlapped the experimental data for the ν branch along both the $\overline{\Gamma}M$ and $\overline{\Gamma}K$ directions. Next the imaginary part is obtained from the Kramers-Kronig transformation of the real part via Eq. (34). Finally, we use Eq. (35) to calculate the ν -branch-specific *e-p* coupling function, which is plotted in Fig. 11(b). One will notice that $\lambda_{\nu}(\mathbf{q})$ assumes quite large values with a maximum of \approx 3. Averaging over the points in Fig. 11(b) yields $\langle \lambda_{\nu} \rangle = 1.44$.

We note that, although large, this value for the coupling constant is compatible with recent results of high-resolution angle-resolved photoemission spectroscopy measurements of both Bi₂Se₃ and Bi₂Te₃ which give a value $\lambda \approx 3^8$. However, the authors attribute this large value to contributions from *e*-*p* as well as plasmon-spin interactions. It is possible that the latter could account for the residual contribution to the coupling constant. Moreover, recent inelastic HASS surface phonon measurements on Bi (111) (Ref. 24) report $\lambda \approx 1.3$, which is much stronger than the bulk value. We also note that our calculated value of $\langle \lambda_{\nu} \rangle$ is significantly larger than a recent theoretical calculation²⁵ and an experimental study²⁶ using angle-resolved photoemission spectroscopy.

VI. CONCLUSION

We have measured the low-energy surface phonon dispersion of the strong TI Bi₂Te₃ using HASS techniques. A low-energy z-polarized optical surface phonon mode experiences strong downward renormalization in both the $\bar{\Gamma}\bar{M}$ and $\bar{\Gamma}\bar{K}$ directions, signifying a Kohn anomaly terminating at approximately $2k_F$. Moreover, we find no trace of the ubiquitous Rayleigh surface mode for phonon wave vectors below this value. Our measurements are substantiated by lattice dynamical calculations based upon the PCM, which capture both of these phenomena when interactions between surface PC are taken into account.

In addition, we have performed a calculation of the *e-p* coupling constant for the uniquely dispersive surface optical phonon branch. By fitting our experimental data to a phenomenological model based on the RPA, we find $\langle \lambda_{\nu} \rangle = 1.44$. This exceptionally large value is consistent with a recent experimental study using angle-resolved photoemission spectroscopy, but disagrees with some other theoretical and experimental claims. Thus a consensus about the strength of the *e-p* interaction in Bi₂Te₃ has yet to be reached.

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